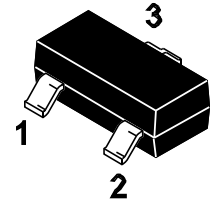


## Features

- Excellent package for good heat dissipation
- High density cell design for ultra low  $R_{DS(on)}$
- $V_{DS} = -30V, I_D = -4.1A$   
 $R_{DS(on)} < 65m\Omega @ V_{GS} = -10V$

## SOT-23



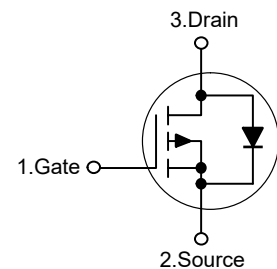
1. Gate 2. Source 3. Drain

Marking Code: R1

## Applications

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

## Schematic Diagram



## Absolute Maximum Ratings

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$-V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	V
Drain Current-Continuous	$-I_D$	4.1	A
Drain Current-Pulsed <sup>Note1</sup>	$-I_{DM}$	20	A
Maximum Power Dissipation	$P_D$	1.2	W
Junction Temperature	$T_J$	150	°C
Storage Temperature Range	$T_{STG}$	-55 to +150	°C

## Thermal Characteristics

Thermal Resistance, Junction-to-Ambient <sup>Note2</sup>	$R_{\theta JA}$	104	°C/W
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**Electrical Characteristics**

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	$-V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	30	--	--	V
Zero Gate Voltage Drain Current	$-I_{DSS}$	$V_{DS}=-30V, V_{GS}=0V$	--	--	1	$\mu A$
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 12V, V_{DS}=0V$	--	--	$\pm 100$	nA
Gate Threshold Voltage <sup>Note3</sup>	$-V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	0.7	0.9	1.3	V
Drain-Source On-Resistance <sup>Note3</sup>	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-4.1A$	--	48	65	m $\Omega$
		$V_{GS}=-4.5V, I_D=-3A$	--	56	85	m $\Omega$
Forward Transconductance <sup>Note3</sup>	$g_{FS}$	$V_{DS}=-5V, I_D=-4.1A$	--	10	--	S
<b>Dynamic Characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=-15V, V_{GS}=0V, f=1MHz$	--	780	--	pF
Output Capacitance	$C_{oss}$		--	80	--	pF
Reverse Transfer Capacitance	$C_{rss}$		--	65	--	pF
Gate Resisitance	$R_g$	$V_{DS}=0V, V_{GS}=0V, f=1MHz$	--	6.5	--	$\Omega$
<b>Switching Characteristics</b>						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=-15V, I_D=-4.1A,$ $V_{GS}=-10V, R_G=6\Omega$	--	7	--	nS
Turn-on Rise Time	$t_r$		--	3	--	nS
Turn-off Delay Time	$t_{d(off)}$		--	30	--	nS
Turn-off Fall Time	$t_f$		--	12	--	nS
Total Gate Charge	$Q_g$	$V_{DS}=-15V,$ $I_D=-4.1A, V_{GS}=-4.5V$	--	8.5	--	nC
Gate-Source Charge	$Q_{gs}$		--	1.8	--	nC
Gate-Drain Charge	$Q_{gd}$		--	2.7	--	nC
<b>Source-Drain Diode Characteristics</b>						
Diode Forward Voltage <sup>Note3</sup>	$-V_{SD}$	$V_{GS}=0V, I_S=-4.1A$	--	--	1.2	V
Diode Forward Current <sup>Note2</sup>	$-I_S$		--	--	4.1	A

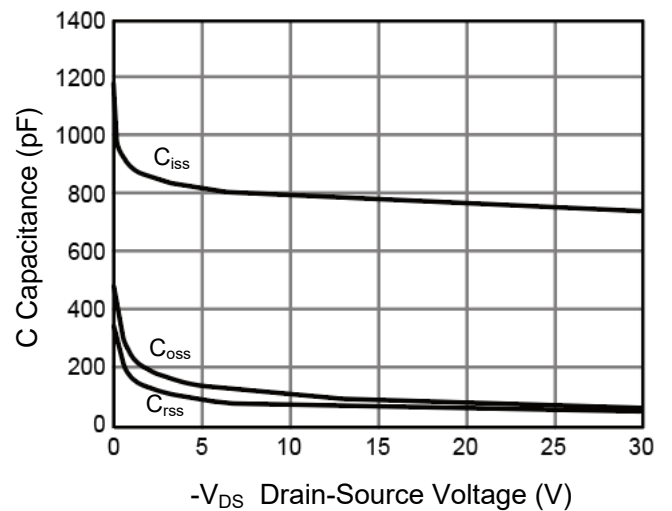
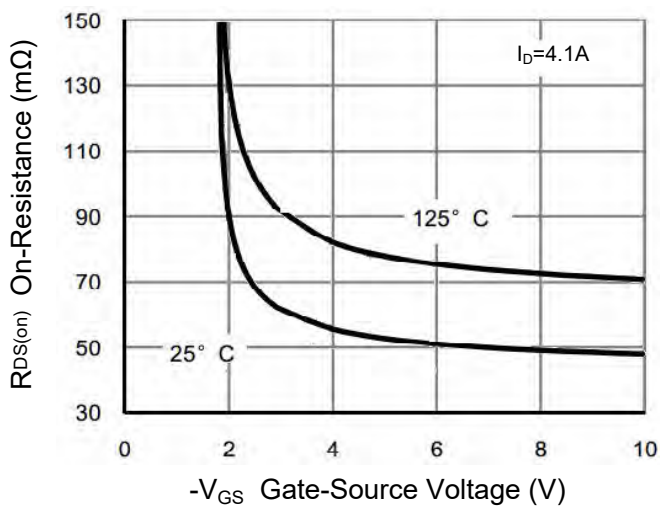
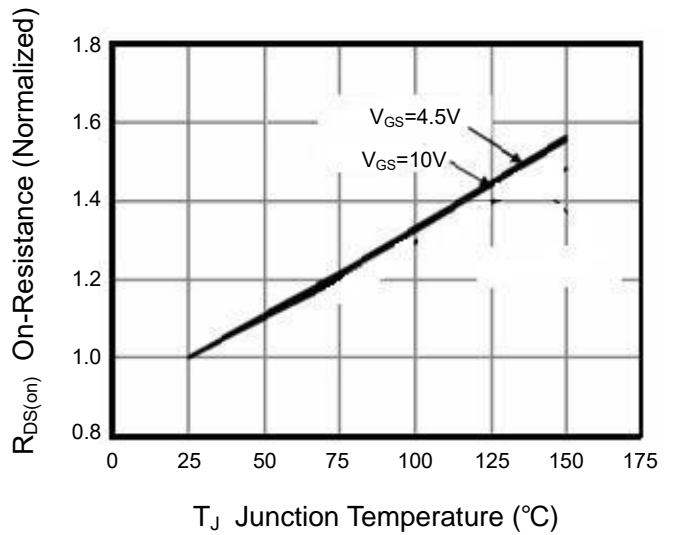
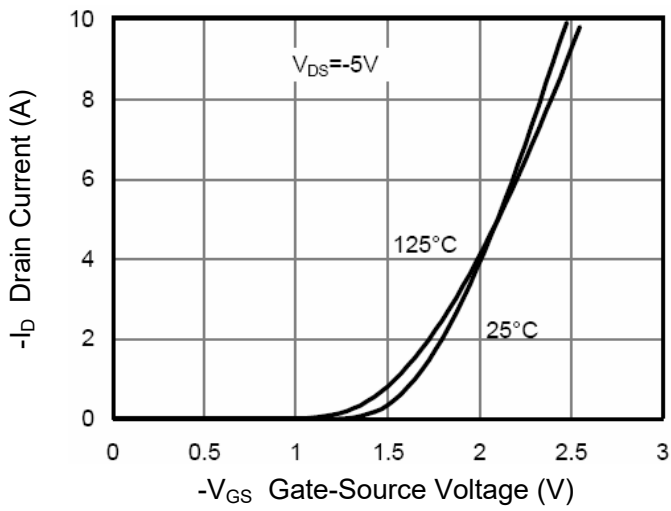
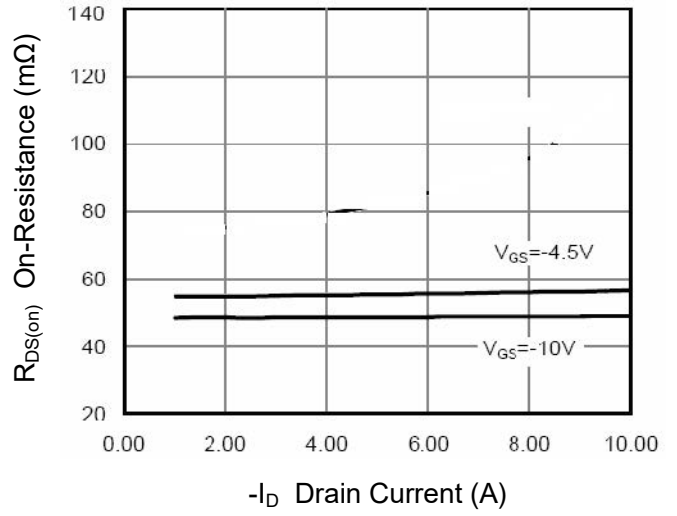
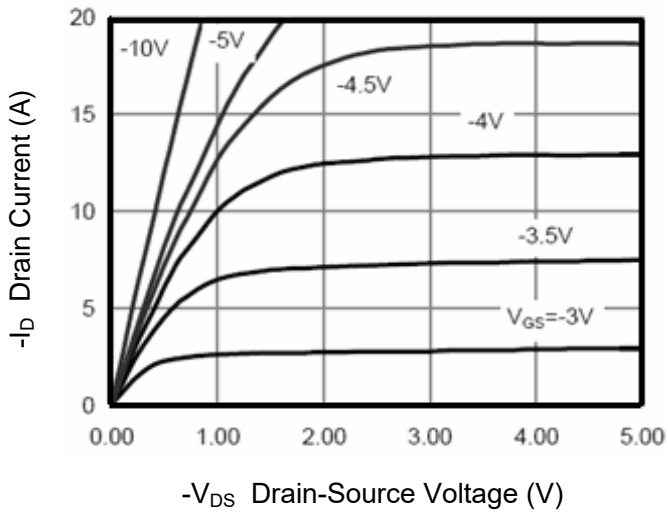
Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature.

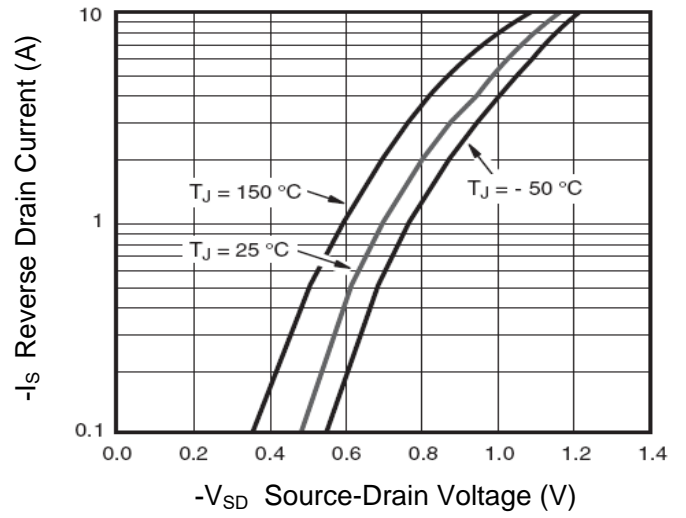
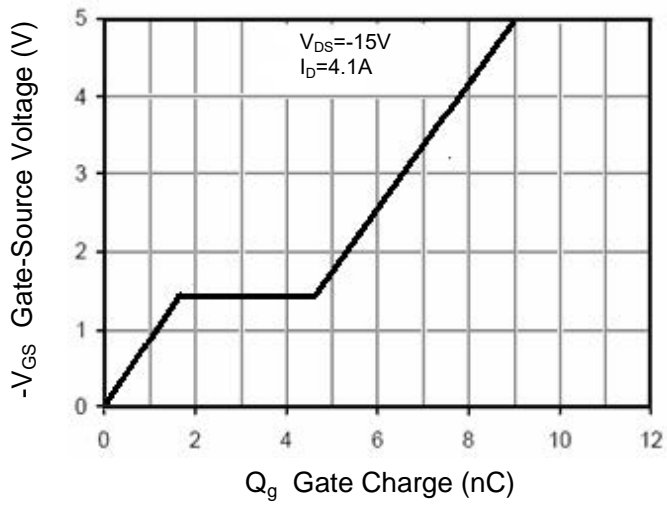
 2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.

 3. Pulse Test: Pulse width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$ .



Typical Characteristic Curves



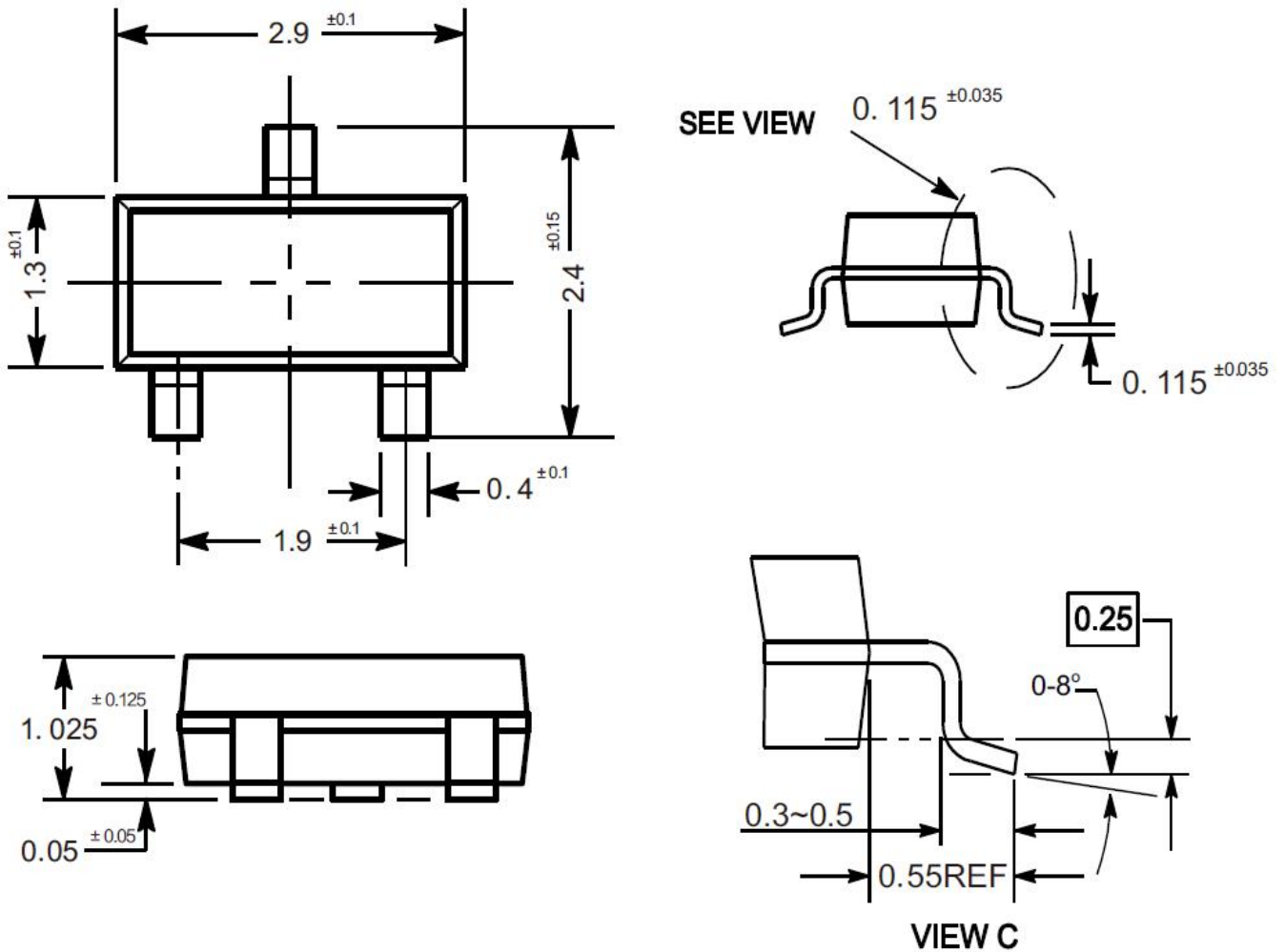




Package Outline

SOT-23

Dimensions in mm



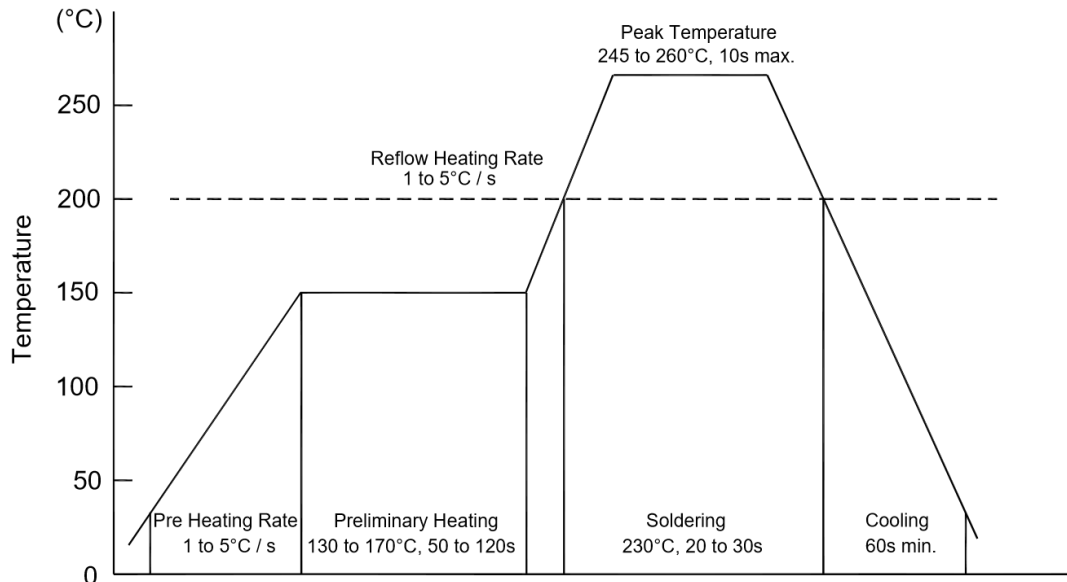
Ordering Information

Device	Package	Shipping
AO3401PSA	SOT-23	3,000PCS/Reel&7inches



## Conditions of Soldering and Storage

### ◆ Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

### ◆ Conditions of hand soldering

- Temperature: 370 °C
- Time: 3s max.
- Times: one time

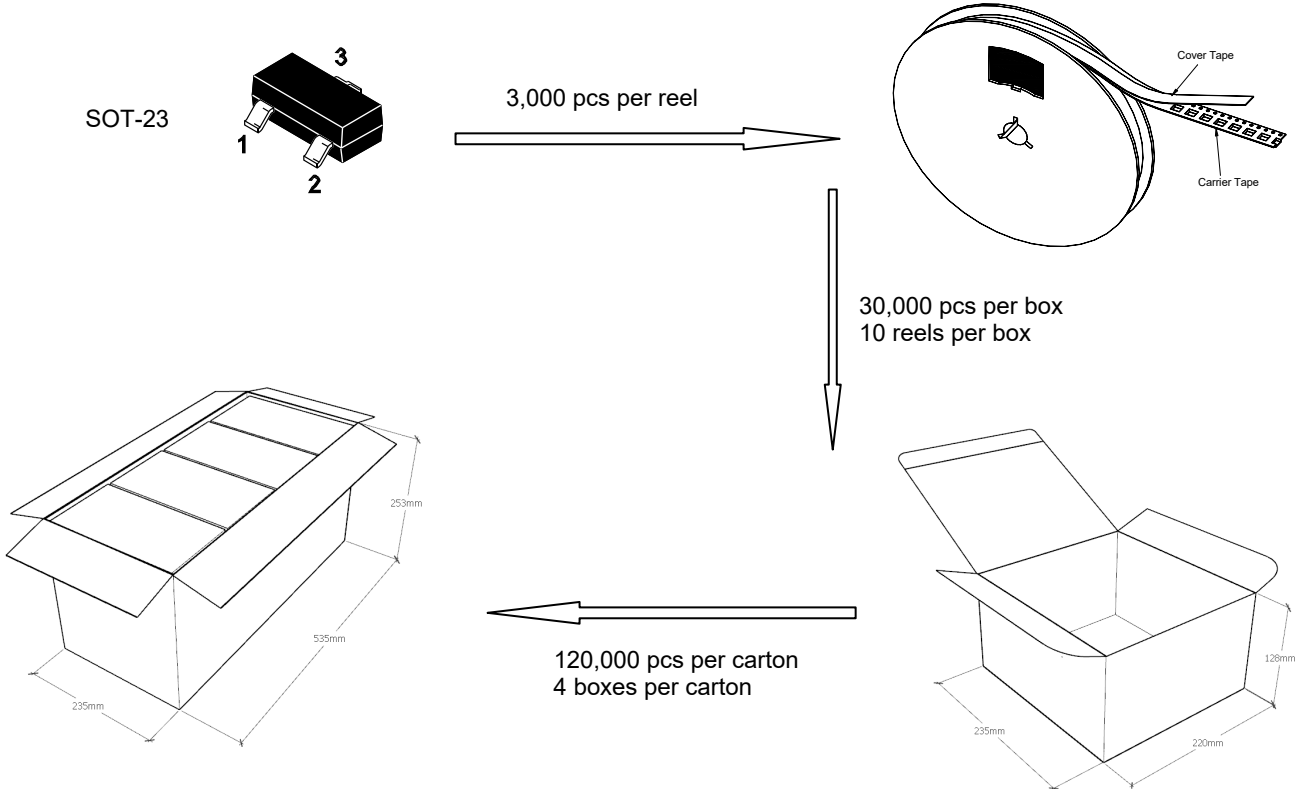
### ◆ Storage conditions

- **Temperature**  
5 to 40 °C
- **Humidity**  
30 to 80% RH
- **Recommended period**  
One year after manufacturing

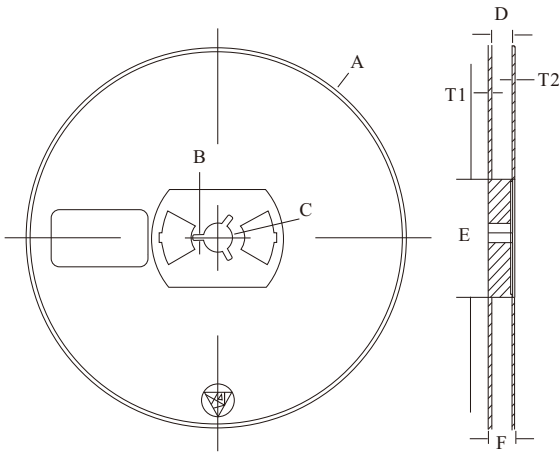


Package Specifications

- The method of packaging

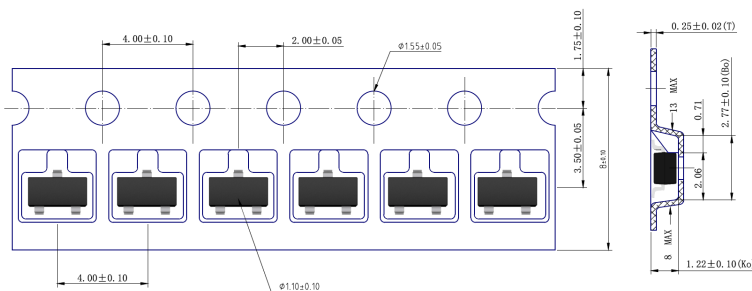


◆ Embossed tape and reel data



Symbol	Value (unit: mm)
A	∅ 177.8±1
B	2.7±0.2
C	∅ 13.5±0.2
E	∅ 54.5±0.2
F	12.3±0.3
D	9.6+2/-0.3
T1	1.0±0.2
T2	1.2±0.2

Reel (7")



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[MCQ7328-TP](#) [SSM3J143TU,LXHF](#) [DMN12M3UCA6-7](#) [PJMF280N65E1\\_T0\\_00201](#) [PJMF380N65E1\\_T0\\_00201](#)  
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